Photocathode developments for robust PICOSEC Micromegas precise-timing detectors

MARTA LISOWSKA

ON BEHALF OF THE CERN GAS DETECTORS DEVELOPMENT TEAM AND THE PICOSEC MICROMEGAS COLLABORATION

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Detector concept

• **PICOSEC Micromegas:** a gaseous detector aiming at achieving a time resolution of tens of picoseconds for MIPs



J. Bortfeldt et al., <u>NIM A 903 (2018) 317</u>

• First single-pad prototypes achieved a time resolution of σ = 24 ps \rightarrow Potential for further improvement and performance enhancement

Single-pad prototype



PICOSEC amplifier cards



PICOSEC amplifier design:
A. Utrobičić, et al. <u>JINST 18 (2023) C07012</u>
based on the RF pulse amplifier:
C. Hoarau, et al., <u>JINST 16 (2021) T04005</u>

LeCroy WR8104 oscilloscope



Developments towards applicable detector

- **Objective:** Robust tileable multi-channel detector modules for large-area coverage
- Detector optimisation: gaps thickness, fields settings, operating gas
 Stability and robustness: resistive Micromegas, robust photocathodes
 Single-pad prototypes to understand detector behaviour, more costeffective and practical
 - Large area coverage:

100-channel prototypes, tileable modules

• Scalable electronics:

dedicated amplifiers, multi-channel digitisers





PICOSEC photocathodes

Component parts

- Radiator: 3 mm MgF₂
 - thickness influences the UV photon production and the Cherenkov cone size
- Interfacial conductive layer: 3 nm Cr
 - provide a contact for the HV to the photocathode
 - mitigate charging-up effects and voltage drops under high-rate conditions
 - Ti as an alternative

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- Semi-transparent photocathode: 18 nm Csl
 - excellent time resolution but not a robust solution
 - dependance between the time resolution and number of photoelectrons $N_{\rm PE}$:

$$\sigma_{\rm MIP} = \frac{\sigma_{\rm SPE}}{\sqrt{N_{PE}}} \rightarrow \sigma_{\rm SPE} = {\rm const} \rightarrow \sigma_{\rm MIP} \sim \frac{1}{\sqrt{N_{PE}}}$$

where: $\sigma_{\rm MIP}$ - time resolution for MIPs, σ_{SPE} - time resolution for single photoelectrons (SPE)





A. Utrobičić et al., arXiv:2406.05657

PICOSEC photocathodes

CsI photocathode and the alternatives

- Single-pad prototype:
 - 3 mm MgF₂ + 3 nm Cr + 18 nm CsI photocathode
 - + high QE with N_{PE} exceeding 12 per MIP^[1],

thereby contributing to its excellent time resolution

- can be damaged by ion back flow (IBF), discharges
- sensitive to humidity (during assembly)
- Need to search for alternative materials:
 - \rightarrow Diamond-Like Carbon (DLC)
 - \rightarrow Boron Carbide (B₄C)
 - \rightarrow Nanodiamonds
 - \rightarrow Carbon nano-structures





CsI photocathode damaged by IBF

L. Sohl, PhD dissertation



^[1] J. Bortfeldt et al., <u>NIM A 903 (2018) 317</u>



Experimental methodology

Measurements with particle beams

- **R&D activities:** From simulations and design, through production and assembly, to measurements and analysis
- **Objective of the test beam campaigns:** to measure the time resolution of the detectors assembled in various configurations
- **Beam type:** CERN SPS H4 beam line, 150 GeV/c muons
- Experimental setup: tracking/timing/triggering telescope

 → Triple-GEM detectors for particle tracking σ_{GEM} < 80 μm
 → MCP-PMT for timing reference and DAQ trigger σ_{MCP} ≈ 6 ps
 → PICOSEC Micromegas (MM) detectors under test



Experimental methodology

Number of photoelectrons

- Perform single photoelectron (SPE) measurements¹ using a UV light-emitting diode (LED) • and multiple photoelectron measurements using a MIP beam
- Determine the maximum amplitude for each waveform
- Plot a histogram of all maximum amplitudes for both cases ٠
- Fit the noise component using a Gaussian, ٠ while the signal component using a Pólya
- Divide the mean amplitude of the MIP V_{MIP} ٠ by the mean amplitude of the SPE V_{SPF} to obtain N_{PF} for a given photocathode:

$$N_{PE} = \frac{V_{MIP}}{V_{SPE}}$$

¹Extraction of one photoelectron at a time was ensured by setting the LED to a low rate and monitoring the waveforms on the oscilloscope to confirm that events did not overlap but were well separated in time





M. Lisowska et al., arXiv:2407.09953

Noise → Gaussian

0.05

Signal → Pólya

0.1

0.15

Signal amplitude, V

0.2

Events

 10°

0

Diamond-Like Carbon – production

- DLC deposited at USTC showed good performance and robustness
- Depositions using a magnetron sputtering technique at the CERN MPT workshop to explore capabilities
- <u>Two deposition campaigns</u>: DLC photocathodes done with layer thicknesses ranging from 1.5 nm to 100 nm



Pulsed DC magnetron vacuum deposition machine



Samples inside the holder with different sizes and masks



Holders with samples attached to the drum



Loading the drum into the chamber

Huge thanks to Serge, Rui, Gianfranco, Givi, Louise Miranda and Thomas for the opportunity to do the deposition as well as all the help during the procedure!

Details on the machine: MPGD School 2024, R. de Oliveira: <u>link</u>



Diamond-Like Carbon – laboratory measurements

- **Transparency** measurements in the UV-VIS range obtained with a spectrophotometer •
- The data demonstrate a correlation between the estimated thicknesses and the measured transparency ٠
- Surface resistivity measurements performed using a picoammeter to confirm if the estimated thicknesses follow the expected trend ٠
- Higher resistivity for DLC on MgF₂ than DLC on glass \rightarrow DLC on MgF₂ is thinner, potentially due to the lower adhesion of the crystal ٠



DLC photocathodes with varying layer thicknesses

M. Lisowska et al., arXiv:2407.09953

Successful deposition of DLC

^{of} different layer thickness

Diamond-Like Carbon – particle beam measurements

- DLC photocathodes, ranging in thickness from 1.5 nm to 3.5 nm, were characterised during particle beam measurements
- Detector with a 1.5 nm DLC deposited directly on the radiator, exhibited $\sigma = 31.9 \pm 1.3 \text{ ps}$; thicker samples ~4 ps worse resolution
- Evaluation of the samples including 3 nm Cr interfacial layer showed a transparency decrease by ~30% and a 2 ps worse time resolution
- To enhance UV photon production, a 5 mm MgF₂ radiator with a 2.5 nm DLC was tested



Boron Carbide

- B₄C photocathodes deposited at CEA-Saclay and ESS showed promising results
- Samples of 3 mm MgF₂ + 3 nm Cr + B₄C from 7.5 nm to 15 nm showed transparency from 40% to 20% (@180 nm)
- Detector with a 9 nm B_4C and a 3 nm Cr interfacial layer exhibited $\sigma = 34.5 \pm 1.5$ ps
- Thicker samples showed up to ~ 10 ps worse resolution



*B*₄*C* sample in the sputtering machine





M. Lisowska et al., <u>arXiv:2407.09953</u>

45

0.9

0.8

0.7

0.6

0.5

0.4

0.3

0.2

0.1

Efficiency DUT

Titanium as a conductive interlayer

- The MgF₂ substrate exhibits 80% transparency @180 nm, it decreases to 45% with adding the Cr layer and drops to 10% with the CsI
- The 35% reduction in transparency after adding the Cr layer is primarily due to light absorption, which diminishes the number of photons reaching the photocathode → This issue could be mitigated by using a different contact material with better transparency
- Titanium (Ti) is the most favourable candidate, with ~15% higher transparency compared to Cr



Graphene as a protective layer

- In studies using graphene as a photocathode, a 2.5–3 nm Ti layer produced $N_{PE} \approx 4.3$ and showed a time resolution $\sigma < 30$ ps
- Adding graphene partially screens the photoelectron (PE) emission from the Ti, with the monolayer (ML) screening \sim 30% and the bilayer (BL) and trilayer (TL) screening \sim 50% of the PEs \rightarrow time resolution down to $\sigma \approx$ 36 ps for Ti + a ML of graphene
- Graphene could be considered as a protective layer



Graphene photocathodes with varying layer number, G. Orlandini



Photocathode characterisation Sensitivity to humidity

- Photocathodes with Cr + CsI show traces of no CsI with accumulation of the material at the ends
- Photocathodes with Ti + CsI also show traces of no CsI but without accumulation dots of the material
- Both DLC and B₄C photocathodes have uniform layers with some scratches on the top, most likely due to the sample handling









Towards applicable detector

Stable and robust prototype

• First measurement combining a single-pad 15 mm dia. resistive Micromegas, a DLC photocathode and an amplifier embedded into

the outer PCB showed stable performance and achieved a **time resolution of** σ = **31.4** ± **0.6 ps**, capturing fully contained events



M. Lisowska et al., <u>arXiv:2407.09953</u>

Towards applicable detector

100-channel module performance

- Several pads of the 100-channel module were characterised during particle beam measurements with an oscilloscope
- Prototype equipped with a **CsI photocathode** achieved a **time resolution of \sigma \approx 18 ps**
- Detector assembled with a **DLC photocathode** obtained a **time resolution of \sigma \approx 35 \text{ ps}**
- First measurements with a **B**₄**C photocathode** showed a **time resolution of** $\sigma \approx 41$ ps



E. Chatzianagnostou, <u>MSc thesis</u> (2022)



for individual pads and fully contained events

Conclusions

- Intensive studies on robust photocathodes resulted in achieving great time resolutions of $\sigma \approx 32$ for DLC, $\sigma \approx 34.5$ ps for B₄C and $\sigma \approx 36$ ps for Ti + a ML of graphene photocathodes
- Carbon-based materials displayed notably greater resistance to discharges and humidity and have been reused across multiple test beam campaigns, showing no deterioration in time resolution
- Measurements confirmed that the excellent timing can be transferred to a 100-channel module, achieving $\sigma \approx 18$ ps for CsI, $\sigma \approx 35$ ps for DLC and $\sigma \approx 41$ ps for B₄C photocathodes
- The efforts dedicated to advancing the detectors increase the feasibility of the PICOSEC concept for experiments requiring sustained performance while maintaining excellent timing precision

Future perspectives

- Ageing studies of the DLC and B₄C, response to IBF
- Deposition of the B₄C and a mix of DLC+B₄C photocathodes at the CERN MPT workshop
- Production of 10x10 cm² area robust photocathodes at the CERN MPT workshop
- Search for other alternative materials (carbon nano-structures, nanodiamonds low efficiency)



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PICOSEC Micromegas Collaboration

M. Lisowska^{1,2,*}, Y. Angelis³, J. Bortfeldt⁴, F. Brunbauer¹, E. Chatzianagnostou³, K. Dehmelt⁵, G. Fanourakis⁶, K. J. Floethner^{1,7}, M. Gallinaro⁸, F. Garcia⁹, P. Garg⁵, I. Giomataris¹⁰, K. Gnanvo¹¹, T. Gustavsson¹², F.J. Iguaz¹⁰, D. Janssens^{1,13,14}, A. Kallitsopoulou¹⁰, M. Kovacic¹⁵, P. Legou¹⁰, J. Liu¹⁶, M. Lupberger^{7,17}, S. Malace¹¹, I. Maniatis^{1,3}, Y. Meng¹⁶, H. Muller^{1,17}, E. Oliveri¹, G. Orlandini^{1,18}, T. Papaevangelou¹⁰, M. Pomorski¹⁹, L. Ropelewski¹, D. Sampsonidis^{3,20}, L. Scharenberg^{1,17}, T. Schneider¹, L. Sohl¹⁰, M. van Stenis¹, Y. Tsipolitis²¹, S.E. Tzamarias^{3,20}, A. Utrobicic²², R. Veenhof^{1,23}, X. Wang¹⁶, S. White^{1,24}, Z. Zhang¹⁶, and Y. Zhou¹⁶

¹European Organization for Nuclear Research (CERN), CH-1211, Geneve 23, Switzerland ²Université Paris-Saclay, F-91191 Gif-sur-Yvette, France ³Department of Physics, Aristotle University of Thessaloniki, University Campus, GR-54124, Thessaloniki, Greece ⁴Department for Medical Physics, Ludwig Maximilian University of Munich, Am Coulombwall 1, 85748 Garching, Germany ⁵Stony Brook University, Dept. of Physics and Astronomy, Stony Brook, NY 11794-3800, USA ⁶Institute of Nuclear and Particle Physics, NCSR Demokritos, GR-15341 Agia Paraskevi, Attiki, Greece ⁷Helmholtz-Institut für Strahlen- und Kernphysik, University of Bonn, Nußallee 14–16, 53115 Bonn, Germany ⁸Laboratório de Instrumentação e Física Experimental de Partículas, Lisbon, Portugal ⁹Helsinki Institute of Physics, University of Helsinki, FI-00014 Helsinki, Finland ¹⁰IRFU, CEA, Université Paris-Saclay, F-91191 Gif-sur-Yvette, France ¹¹Jefferson Lab, 12000 Jefferson Avenue, Newport News, VA 23606, USA ¹²LIDYL, CEA, CNRS, Universit Paris-Saclay, F-91191 Gif-sur-Yvette, France ¹³Inter-University Institute for High Energies (IIHE), Belgium ¹⁴Vrije Universiteit Brussel, Pleinlaan 2, 1050 Brussels, Belgium ¹⁵Faculty of Electrical Engineering and Computing, University of Zagreb, 10000 Zagreb, Croatia ¹⁶State Key Laboratory of Particle Detection and Electronics, University of Science and Technology of China, Hefei 230026, China ¹⁷Physikalisches Institut, University of Bonn, Nußallee 12, 53115 Bonn, Germany ¹⁸Friedrich-Alexander-Universität Erlangen-Nürnberg, Schloßplatz 4, 91054 Erlangen, Germany ¹⁹CEA-LIST, Diamond Sensors Laboratory, CEA Saclay, F-91191 Gif-sur-Yvette, France ²⁰Center for Interdisciplinary Research and Innovation (CIRI-AUTH), Thessaloniki 57001, Greece ²¹National Technical University of Athens, Athens, Greece ²²Institute Ruder Bosković Institute, Bijenička cesta 54, 10000, Zagreb, Croatia ²³Bursa Uludağ University, Görükle Kampusu, 16059 Niufer/Bursa, Turkey ²⁴University of Virginia, USA



Thank you for your attention!

CONTACT: MARTA.LISOWSKA@CERN.CH

Back up slides

Pre-amplification gap

- Higher electric field \rightarrow Early avalanche \rightarrow **Reduced Signal Arrival Time (SAT)** •
- Thinner pre-amplification gap limits the direct ionisation and grants a stable • operation



Pre-ionisation track

Pre-amplification avalanche



Garfield++ simulations

J. Bortfeldt et al., NIM A 993 (2021) 165049

QE measurements - Reflective mode







QE measurements - Transmission mode







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Ageing studies – Irradiation mode



3. Irradiated sample (grounded): Attraction of ions from avalanche Accumulation of charge

2. Multiplication wires (positive HV): Attraction of primary electrons Avalanche multiplication Production of electrons and ions

 X-ray beam in a gas chamber: lonization of particles
 Creation of primary charge







Ageing studies - Csl

Signal analysis

٠

- Quantifying the PICOSEC detector's time resolution requires a reference device with a superior timing precision: MCP-PMT $\sigma_{MCP} \approx 6$ ps
- Leading edge of the signal fitted using a sigmoid function timestamps determined at 20% of the signal amplitude (CFD method)
- Signal Arrival Time (SAT) computed as a difference between the timestamps: SAT = $t_{PICO} t_{MCP}$ Tracker GEM 3
- The histogram of SAT values fitted with a double Gaussian function Tracker GEM 2



Double Gaussian function

The histogram of SAT values was fitted with a double Gaussian function, which effectively approximates the shape of the distribution and accounts for the variations between the SAT and the e-peak charge. The double Gaussian function is given by the equation

$$f(\Delta t) = N \left[a \exp\left(-\frac{\Delta t - \mu}{2\sigma_{core}^2}\right) + (1 - a) \exp\left(-\frac{\Delta t - \mu}{2\sigma_{tail}^2}\right) \right],$$

where N is a scaling factor, $a \in [0, 1]$ is a weighting parameter, μ is the mean of the distribution, σ_{core} is the standard deviation of the core Gaussian, and σ_{tail} is the standard deviation of the Gaussian describing the tail. The weighting parameter between the two Gaussian components enables the determination of the combined standard deviation σ_{comb}^2 of the overall distribution:

$$\sigma_{comb}^2 = a \; \sigma_{core}^2 + (1-a) \; \sigma_{tail}^2$$

This combined standard deviation σ_{comb}^2 represents the time resolution of the detector system.



Signal analysis

• In addition to time resolution, several other parameters are evaluated and compared across the prototypes





10-90 % of max amplitude to see the influence of capacitance

Rise time of the leading edge



Detection efficiency depending on N_{PF}



All reported results concern fully contained events

due to the Cherenkov cone

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Nanodiamonds



Large-area coverage

100-channel module design



PICOSEC amplifier cards



A. Utrobičić, et al. <u>JINST 18 (2023) C07012</u>

LeCroy WR8104 oscilloscope or SAMPIC Waveform TDC



D. Breton et al., NIM A 835 (2016) 51